Triacs

Silicon Bidirectional Thyristors

Designed primarily for industrial and consumer applications for full wave control of ac loads such as appliance controls, heater controls, motor controls, and other power switching applications.

- All Diffused and Glass–Passivated Junctions for Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance and High Heat Dissipation
- Center Gate Geometry for Uniform Current Spreading
- Gate Triggering Guaranteed in Four Modes
- **%** Indicates UL Registered File #E69369
- Device Marking: Logo, Device Type, e.g., MAC229A8FP, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage ⁽¹⁾ (T _J = -40 to 110°C, Sine Wave 50 to 60 Hz, Gate Open)	VDRM, VRRM		Volts
MAC229A8FP MAC229A10FP		600 800	
On-State RMS Current (T _C = 80°C) Full Cycle Sine Wave 50 to 60 Hz	I _{T(RMS)}	8.0	Amps
Peak Non–Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T _J = 110°C)	ITSM	80	Amps
Circuit Fusing Consideration (t = 8.3 ms)	l ² t	26	A ² s
Peak Gate Current $(t \le 2 \mu s, T_C = 80^{\circ}C)$	I _{GM}	±2.0	Amps
Peak Gate Voltage (t ≤ 2 μs, T _C = 80°C)	VGМ	±10	Volts
Peak Gate Power (t \leq 2 µs,T _C = 80°C)	PGM	20	Watts
Average Gate Power $(T_C = 80^{\circ}C, t \leq 8.3 \text{ ms})$	PG(AV)	0.5	Watt
RMS Isolation Voltage (T _A = 25°C, Relative Humidity ≤ 20%) (%)	V _(ISO)	1500	Volts
Operating Junction Temperature Range	TJ	-40 to 110	°C
Storage Temperature Range	T _{stg}	-40 to 150	°C
Mounting Torque	_	8.0	in. lb.

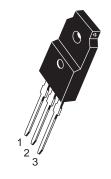
⁽¹⁾ V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.



http://onsemi.com

ISOLATED TRIAC (9\) 8 AMPERES RMS 600 thru 800 VOLTS





ISOLATED TO-220 Full Pack CASE 221C STYLE 3

PIN ASSIGNMENT			
1	Main Terminal 1		
2	Main Terminal 2		
3	Gate		

ORDERING INFORMATION

Device	Package	Shipping
MAC229A8FP	ISOLATED TO220FP	500/Box
MAC229A10FP	ISOLATED TO220FP	500/Box

⁽²⁾ The case temperature reference point for all TC measurements is a point on the center lead of the package as close as possible to the plastic body.

THERMAL CHARACTERISTICS

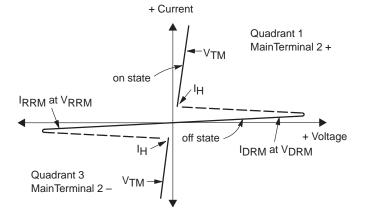
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{ heta JC}$	2.2	°C/W
Thermal Resistance, Case to Sink	$R_{\theta}CS$	2.2	°C/W
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	60	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS		•		•	•	
Peak Repetitive Blocking Current ⁽¹⁾ (V _D = Rated V _{DRM} , V _{RRM} ; Open Gate)	T _J = 25°C T _J = 110°C	I _{DRM} , I _{RRM}		_	10 2.0	μA mA
ON CHARACTERISTICS				•		
Peak On-State Voltage (I _{TM} = ±11 A Peak, Pulse Width ≤ 2 ms, Duty Cycle ≤	≤ 2%)	VTM		_	1.8	Volts
Gate Trigger Current (Continuous dc) $ (V_D=12\ V,\ R_L=100\ \Omega) \\ MT2(+),\ G(+);\ MT2(+),\ G(-);\ MT2(-),\ G(-) \\ MT2(-),\ G(+) $		IGT		_	10 20	mA
Gate Trigger Voltage (Continuous dc) $ (V_D=12\ V,\ R_L=100\ \Omega) $ $ MT2(+),\ G(+);\ MT2(+),\ G(-);\ MT2(-),\ G(-) $ $ MT2(-),\ G(+) $		VGT	_	_	2.0 2.5	Volts
Gate Non–Trigger Voltage (Continuous dc) (VD = 12 V, TC = 110 $^{\circ}$ C, RL = 100 Ω) All Four Quadrants		V _{GD}	0.2	_	_	Volts
Holding Current (V _D = 12 Vdc, Initiating Current = ±200 mA, Gate Open)		lн	-	_	15	mA
Gate–Controlled Turn–On Time (V _D = Rated V _{DRM} , I _{TM} = 16 A Peak, I _G = 30 mA)	^t gt	-	1.5	_	μs	
DYNAMIC CHARACTERISTICS		•		•	•	
Critical Rate of Rise of Off–State Voltage (V _D = Rated V _{DRM} , Exponential Waveform, T _C = 110°C)		dv/dt	_	25	_	V/μs
Critical Rate of Rise of Commutation Voltage (VD = Rated VDRM, ITM = 11.3 A, Commutating di/dt = 4.1 A/ms, Gate Unenergized, TC = 80°C)		dv/dt(c)	_	5.0	_	V/μs

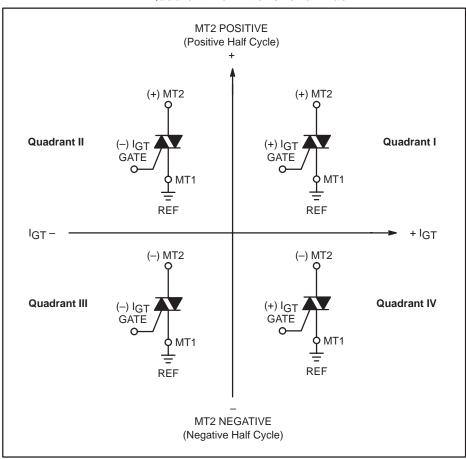
⁽¹⁾ Ratings apply for open gate conditions. Devices shall not be tested with a constant current source for blocking voltage such that the voltage applied exceeds the rated blocking voltage.

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
VDRM	Peak Repetitive Forward Off State Voltage
IDRM	Peak Forward Blocking Current
VRRM	Peak Repetitive Reverse Off State Voltage
IRRM	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
lΗ	Holding Current

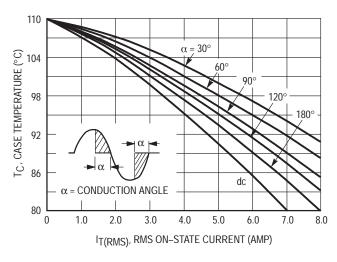


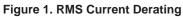
Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.





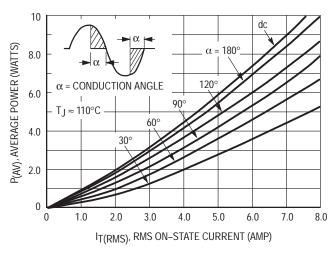
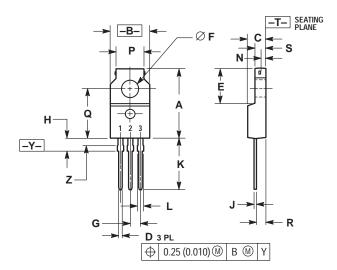


Figure 2. On-State Power Dissipation

PACKAGE DIMENSIONS

ISOLATED TO-220 Full Pack

CASE 221C-02 ISSUE C



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. LEAD DIMENSIONS UNCONTROLLED WITHIN DIMENSION Z.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.680	0.700	17.28	17.78
В	0.388	0.408	9.86	10.36
С	0.175	0.195	4.45	4.95
D	0.025	0.040	0.64	1.01
Ε	0.340	0.355	8.64	9.01
F	0.140	0.150	3.56	3.81
G	0.100 BSC		2.54 BSC	
Н	0.110	0.155	2.80	3.93
J	0.018	0.028	0.46	0.71
K	0.500	0.550	12.70	13.97
L	0.045	0.070	1.15	1.77
N	0.049		1.25	
P	0.270	0.290	6.86	7.36
Q	0.480	0.500	12.20	12.70
R	0.090	0.120	2.29	3.04
S	0.105	0.115	2.67	2.92
Z	0.070	0.090	1.78	2.28

STYLE 3: PIN 1. MT 1





ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

PUBLICATION ORDERING INFORMATION

NORTH AMERICA Literature Fulfillment:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada **Fax**: 303–675–2176 or 800–344–3867 Toll Free USA/Canada

Email: ONlit@hibbertco.com

Fax Response Line: 303-675-2167 or 800-344-3810 Toll Free USA/Canada

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

EUROPE: LDC for ON Semiconductor - European Support

German Phone: (+1) 303-308-7140 (M-F 1:00pm to 5:00pm Munich Time)

Email: ONlit-german@hibbertco.com

French Phone: (+1) 303-308-7141 (M-F 1:00pm to 5:00pm Toulouse Time)

Email: ONlit-french@hibbertco.com

English Phone: (+1) 303–308–7142 (M–F 12:00pm to 5:00pm UK Time)

Email: ONlit@hibbertco.com

EUROPEAN TOLL-FREE ACCESS*: 00-800-4422-3781

*Available from Germany, France, Italy, England, Ireland

CENTRAL/SOUTH AMERICA:

Spanish Phone: 303-308-7143 (Mon-Fri 8:00am to 5:00pm MST)

Email: ONlit-spanish@hibbertco.com

ASIA/PACIFIC: LDC for ON Semiconductor – Asia Support

Phone: 303-675-2121 (Tue-Fri 9:00am to 1:00pm, Hong Kong Time)

Toll Free from Hong Kong & Singapore:

001-800-4422-3781
Email: ONlit-asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center 4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–8549

Phone: 81–3–5740–2745 **Email**: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local Sales Representative.